amplifiers

PAM PROseries

4th GENERATION ECLER PROFESSIONAL AMPLIFIERS.

The use of switching mosfet and the result of innovation in 3 basic aspects of the design make the 6 models of the 4th generation SPM technology the most advanced audio amplifiers in the market.

1.- Protection system based on the SOA (Safe Operating Area).

The SOA is the normal operating area of the MOSFET. The special point on switching Mosfets is that they can support power peaks of three or more times the maximum DC power for very short times, thus making possible for an amplifier to punctually drive a 0.3 ohm load with a 150A current peak. As a consequence of that, the protection circuit must be intelligent and able to take decisions in function of each situation.



· Overload protection.

The overload protection avoids the possible overheating of the Mosfet when the maximum power is exceeded for a time longer than the permitted. The protection system used in these amplifiers is fast, secure, simple and operates for sections. The circuit detects and limits the current so that, for the worst case of drain-source voltage, the maximum power is never exceeded. A high speed logic circuit evaluates how critical the problem is and, in case of danger, disconnects the output signal by means of a relay. The autoreset system acts in a few seconds and reconnects de relay. If the problem is still there, the process will be repited up to 4 times within a maximum period of 5 minutes.

Temperature protection.

A sensor detects when the temperature rises above 90° C and opens the protection relay. This only happens when, after a long period of time, sand, dust or other materials can block or lessen the efficiency of the cooling system.

• DC Out protection.

Avoids the possibility of applying a DC voltage directly to the loudspeakers which would destroy the loudspeaker coils.

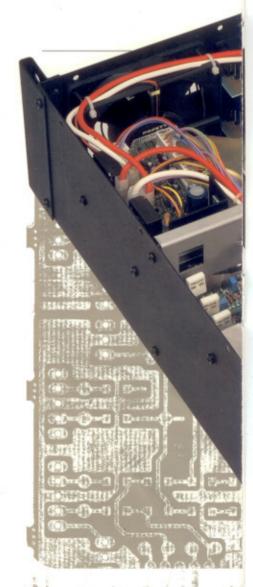
Anticlip protection.

An excessive clipping generates a high-energy pseudo-square signal that affects the sound quality and can even damage the loudspeakers. The anticlip circuit avoids this by reducing the input signal when the output exceeds the preset limits.

The ECLER Professional Series protections are non destructive in opposition to the most commonly destructive protections found in almost all the amplifiers. The destructive protection limits the current when there is an excessive output signal without stopping the amplifier and produces a high degradation of the audio quality. The SPM non destructive protections only act when there is an excessive power dissipation within a minimum preset time. Thus the amplifier can supply a very high impulsional power and take the maximum benefit of the SOA without affecting the sound quality.

2.- Cooling system.

For the same power, the Switching Mosfet heats 15° C less than the conventional Mosfets and 10° C less than bipolar transistors. While the conventional audio Mosfets and the bipolar transistors must be cooled immediatly, the switching Mosfet enables to cool first other components such as the electrolytic capacitors which operating life strongly depends on the temperature.



	PAM300	PAM600	PAM1000	PAM1400	PAM2000 PAM2900	OUTPUT POWER (W RMS, 1 kHz, 1% THD)			PAM1000		PAM2000		
Frequency response	District of the last of the la					4Ω stereo	187 W	352 W	583 W	737 W	990 W	1350 W	
@ max. output power. (-1dB)	7 Hz - 60 kH		60 KHZ		BΩ stereo	126 W	220 W	363 W	451 W	615 W	875 W		
Harmonic distorsion + noise @ 1kHz.	< 0.02%				< 0.03%	252 stereo(*)	275 W	490 W	895 W	1160 W	1260 W	1740 W	
Intermodulation distortion 50 Hz & 7 kHz; 4:1 ratio @ nom, out, power	< 0.03%			.03%		8G bridged	376 W	704 W	1177 W	1474 W			
TIM100	< 0.05% < 0.03%				< 0.03%	16Ω bridged	258 W	451 W	726.W	902 W			
Signal/noise ratio 20 Hz-20 kHz ref.:1W/402	> 85 dB	> 80	0 dB	> 85 dB	> 80 dB	OUTPUT POWER (#) (W RMS, 20 Hz-20 kHz, 0,1% THD)			PAM1000	PAM1400			1
Signal/hoise ratio 20 Hz-20 kHz	> 107 dB	> 105 dB	> 106 dB	> 110 dB	> 108 dB	4Ω stereo	158 W	307 W	510 W	625 W	880 W	1160 W	
nominal power/4Ω						8Ω stereo	108 W	196 W	320 W	385 W	550 W	770 W	
Demping factor Siew rate	> 350 ± 32 Wus	> 310 ± 75 Wus	> 400 ± 80 V/µs	> 420 ± 85 V/µs	> 140 ± 95 Wµs	2Ω stereo(*)	220 W	415 W	704 W	990 W	1090 W	1500 W	1
Channel crosstalk @ 1kHz	Tige within	> 80		1.00 M/s	> 65 dB	8Ω bridged	315 W	615 W	1020 W	1250 W		3100000	1 1
Input sensivity/impedance	9			V47 kΩ		16Ω bridged	218 W	390 W	605 W	772 W			1
Input connector	XLR3 balanced					OUTPUT PEAK POWER W RMS			PAM1000	PAM1400		PAM2600	
Output connector	speak on					2Ω / 1 kHz One channel driven	500 W	900 W	1700 W	2300 W	3260 W	4000 W	
Power consumption @ max. out/402	530 VA	965 VA	1445 VA	1800 VA	2730 VA 3650 VA	(#) Both channels operating after	th warming o	up at -3d8 max	. power				
Front pannel dimensions w x h Chassis dimensions w x h x d	482.6 x 440 x 88		482.6 x 132.		132.5 mm 482.6 x 132.5 x 514 mm								
Weight of the second se	14 kg	15.1 kg	19.7 kg			The air is moved to guarantee the of the amplified transformer, aff where the Most the main circuit is on the front so the front so the main circuit is on the front so	e maximer. The a fter is drefets are tooard to side of the mer are of it and	Operation : an still be placed as to cool the amplifund main. Operation : an still be printed ansform Operation : an still be a still be placed as to be cool the amplifund main. Operation : an still be placed ansform The ECLEF its philosop power will get act happ	intercy. The cools the lower and, final he rest of fier. In circuit the circuit the circuit be er. In circuit be er.	ne air inc the pow r side of ly, is driv f the con it boar circular or oards of the loudspes e ampifier op operation at 2t s safe with it loower supply of 4Q is usual on SPM ample ESTRUCTIVE situation of the raperied of to thave to wait a iffer will rest	ome is o ver capa the mail ven to the mponent d. ore that of 105 µm is 105 µm is	on the back acitors and in circuit b he upper sides. The air of closes the r	side d the oard de of butlet mag- than y of any g factor motifies bections less and obved in keeping evaluable uld only a would at signal ing the
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